# INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Aug 11 IC24 Data Handbook 1998 Apr 28





### 74LVC02A

#### **FEATURES**

- Wide supply range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5V
- CMOS low power consumption
- Direct interface with TTL levels
- 5-volt tolerant inputs, for interfacing with 5-volt logic

#### QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

#### DESCRIPTION

The 74LVC02A is a high performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V/5 V environment.

The 74LVC02A provides the 2-input NOR function.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation delay nA, nB to nY	$\begin{array}{l} C_{L}=50 \text{ pF};\\ V_{CC}=3.3 \text{ V} \end{array}$	2.8	ns
Cl	Input capacitance		5.0	pF
C <sub>PD</sub>	Power dissipation capacitance per gate	Notes 1 and 2	28	pF

#### NOTES:

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W)  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;  $C_L$  = output load capacity in pF;  $f_o$  = output frequency in MHz;  $V_{CC}$  = supply voltage in V;

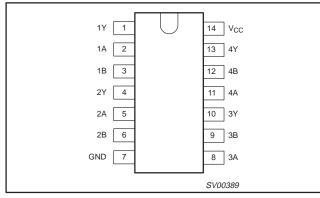
 $\sum (C_L \times V_{CC}^2 \times f_0) =$  sum of the outputs.

2. The condition is  $V_I = GND$  to  $V_{CC.}$ 

#### **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	–40°C to +85°C	74LVC02A D	74LVC02A D	SOT108-1
14-Pin Plastic SSOP Type II	–40°C to +85°C	74LVC02A DB	74LVC02A DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC02A PW	74LVC02APW DH	SOT402-1

#### **PIN CONFIGURATION**

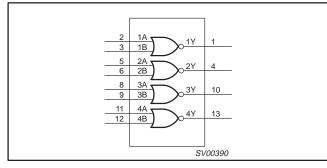


#### **PIN DESCRIPTION**

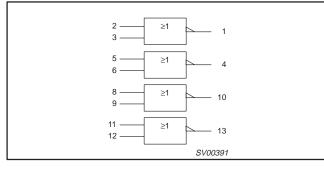
PIN NUMBER	SYMBOL	NAME AND FUNCTION	
1, 4, 10, 13	1Y – 4Y	Data outputs	
2, 5, 8, 11	1A – 4A	Doto inputo	
3, 6, 9, 12	1B – 4B	Data inputs	
7	GND	Ground (0 V)	
14	V <sub>CC</sub>	Positive supply voltage	

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### LOGIC SYMBOL

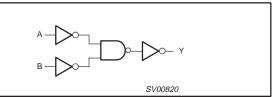


### LOGIC SYMBOL (IEEE/IEC)



### **RECOMMENDED OPERATING CONDITIONS**

### LOGIC DIAGRAM (ONE GATE)



### **FUNCTION TABLE**

INP	OUTPUTS	
nA	nB	nY
L	L	Н
L	Н	L
н	L	L
н	Н	L

NOTES:

H = HIGH voltage level L = LOW voltage level

SYMBOL	DADAMETED		LIN		
	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>CC</sub>	DC supply voltage (for max. speed performance)		2.7	3.6	V
V <sub>CC</sub>	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC Input voltage range		0	5.5	V
Vo	DC output voltage range		0	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free-air		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	V <sub>CC</sub> = 1.2 to 2.7V V <sub>CC</sub> = 2.7 to 3.6V	0 0	20 10	ns/V

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#### **ABSOLUTE MAXIMUM RATINGS<sup>1</sup>**

Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER CONDITIONS		RATING	UNIT
V <sub>CC</sub>	DC supply voltage (for max. speed performance)		-0.5 to +6.5	V
I <sub>IK</sub>	DC input diode current V <sub>1</sub> < 0		-50	mA
VI	DC input voltage	Note 2	-0.5 to +5.5	V
I <sub>OK</sub>	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	± 50	mA
V <sub>O</sub>	DC output voltage	Note 2	-0.5 to V <sub>CC</sub> + 0.5	V
Ι <sub>Ο</sub>	DC output source or sink current	$V_{O} = 0$ to $V_{CC}$	± 50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		±100	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### **DC CHARACTERISTICS**

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

			L	LIMITS Temp = -40°C to +85°C						
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -							
			MIN	TYP <sup>1</sup>	MAX					
N/		$V_{CC} = 1.2V$	V <sub>CC</sub>							
V <sub>IH</sub>	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0			V				
M		$V_{CC} = 1.2V$			GND					
V <sub>IL</sub>	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V			0.8					
	HIGH level output voltage	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V <sub>CC</sub> -0.5							
M		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V <sub>CC</sub> -0.2	V <sub>CC</sub>		v				
V <sub>OH</sub>		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -18\text{mA}$	V <sub>CC</sub> -0.6							
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -24\text{mA}$	V <sub>CC</sub> -0.8							
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12\text{mA}$			0.40					
V <sub>OL</sub>	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	0 V				
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 24 \text{mA}$			0.55	1				
łı	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V \text{ or GND}$		±0.1	±5	μΑ				
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 3.6V; V_1 = V_{CC} \text{ or } \text{GND}; I_0 = 0$		0.1	10	μΑ				
$\Delta I_{CC}$	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$ ; $I_O = 0$		5	500	μA				

NOTES:

1. All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> =  $25^{\circ}$ C.

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### **AC CHARACTERISTICS**

GND = 0 V;  $t_r$  =  $t_f\,\leq\,$  2.5 ns; C\_L = 50 pF

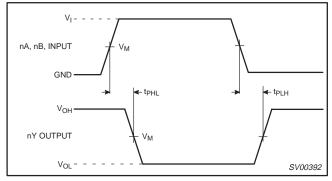
			LIMITS							
SYMBOL PARAMETER		WAVEFORM V <sub>CC</sub> = 3.3V ±0.3V		V <sub>CC</sub> = 2.7V			V <sub>CC</sub> = 1.2V	UNIT		
			MIN	TYP <sup>1</sup>	MAX	MIN	TYP <sup>1</sup>	MAX	TYP	
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nA, nB to nY	Figures 1, 2	1.5	2.8	4.6	1.5	3.2	5.6	11	ns

NOTE:

1. These typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.

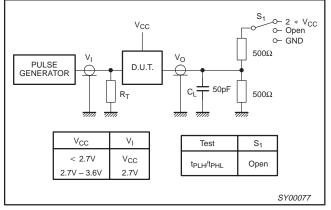
#### **AC WAVEFORMS**

 $V_M$  = 1.5 V at  $V_{CC} \geq 2.7$  V  $V_M$  = 0.5 •  $V_{CC}$  at  $V_{CC} < 2.7$  V  $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load.



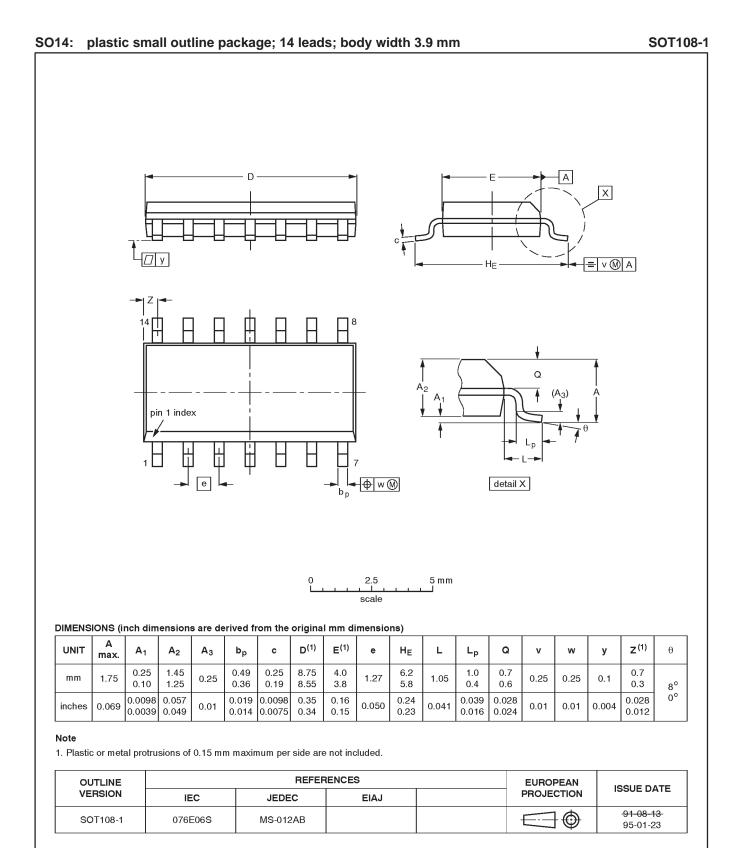
Waveform 1. Input (nA, nB) to output (nY) propagation delays.

### **TEST CIRCUIT**



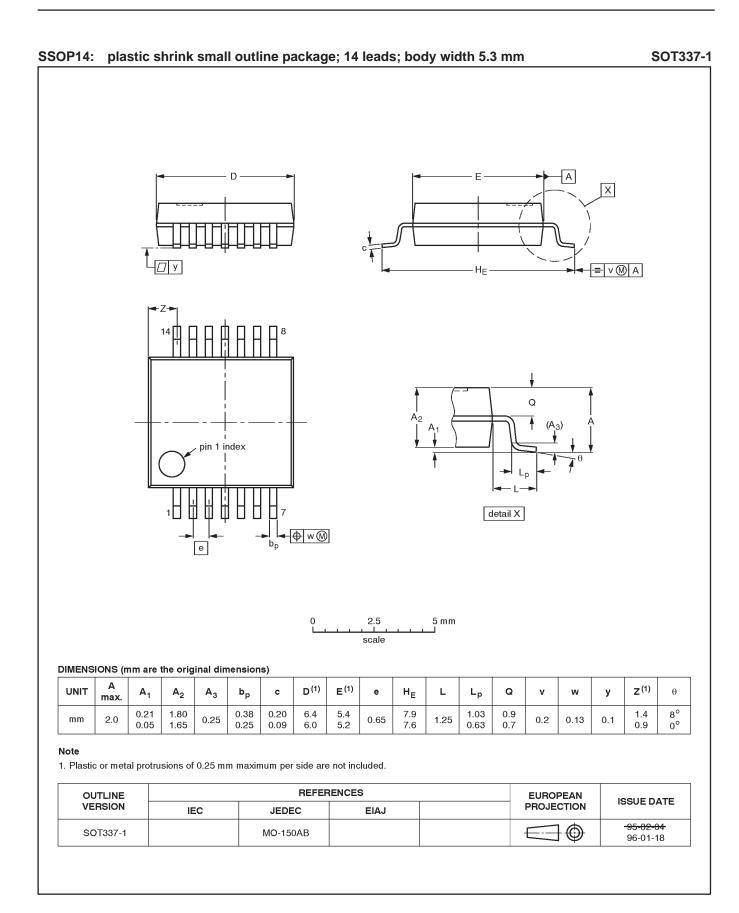
Waveform 2. Load circuitry for switching times.

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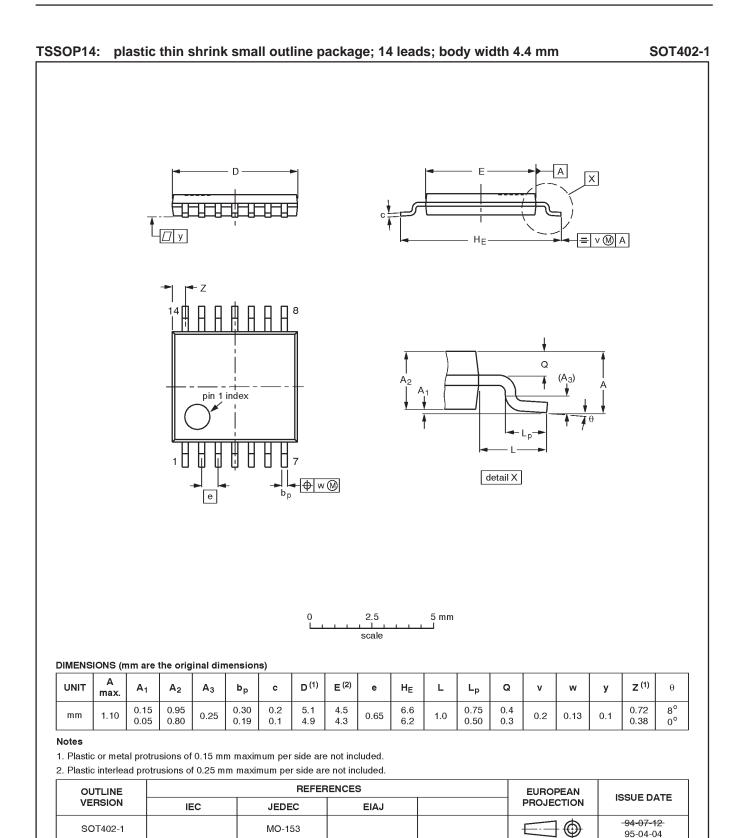


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### 74LVC02A



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NOTES

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DEFINITIONS						
Data Sheet Identification Product Status Definition						
		This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.				
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